Supporting information for

Large tensile-strained BaTiO$_3$ films grown on lattice-mismatched La-doped BaSnO$_3$ bottom electrode

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**Figure S1.** Topographic AFM images for the BaTiO$_3$ films. $t_{BTO} = (a) 20$, (b) 50, (c) 100, and (d) 300 nm.